





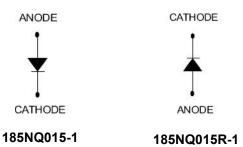
185NQ015/R-1 SCHOTTKY RECTIFIER



Features

- 125℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	15	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =66°C, rectangular wave form	180	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	2700	Α
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25 °C ,I _{AS} =2A,L=4.5mH	9	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =3× V_R typical	2	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	@ 180A, Pulse, T _J = 25 °C	0.35	0.40	V
	V _{F1}	@ 360A, Pulse, T _J = 25 °C	-	0.51	V
	1/-	@ 180A, Pulse, T _J = 75 °C	0.30	0.34	V
	V _{F2}	@ 360A, Pulse, T _J = 75 °C	-	0.45	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	15	60	mA
	I _{R2}	@V _R = rated V _R T _J = 100 °C	1500	3000	mA
	I _{R3}	@V _R = 12V, T _J = 100 °C	1100	2670	mA
	I _{R4}	@V _R = 5V, T _J = 100 °C	700	1620	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	10000	12300	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +125		°C
Storage Temperature	T _{stg}	-	-55 to	+125	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	DC operation	0.3	0	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	T _M	Non-lubricated threads	Mounting Torque	23(min) 29(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

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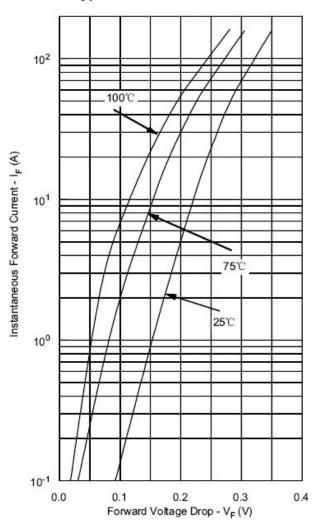




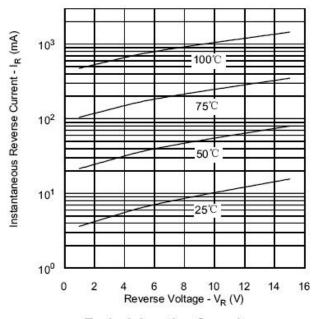


Ratings and Characteristics Curves

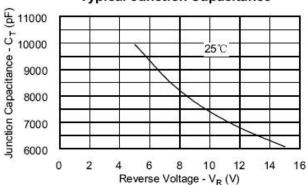
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance

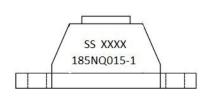


Ordering Information

Device	Package	Shipping	
185NQ015-1	PRM1-1(Pb-Free)	27pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXX is YYWW

1st row SS YYWW
2nd row 185NQ015-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

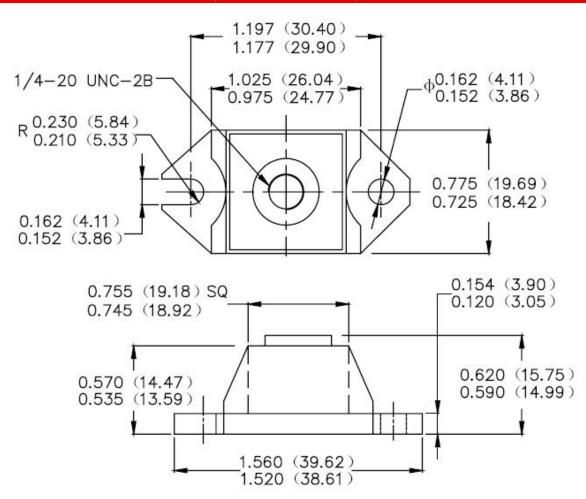
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Mechanical Dimensions PRM1-1 (Inches/Millimeters)



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